



GSID600A120S4B1 Information

Heisener.com

Part Number GSID600A120S4B1

Manufacturer Global Power Technologies Group

Category Discrete Semiconductor Products
Transistors - IGBTs - Modules

Description SILICON IGBT MODULES

Package Module

For the pricing/inventory/lead time, please contact

us

For Reference Only

Website: https://www.heisener.com
E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









GSID600A120S4B1 Specifications

Manufacturer Part Number	GSID600A120S4B1
Manufacturer	Global Power Technologies Group
Category	Discrete Semiconductor Products
	Transistors - IGBTs - Modules
Package	Module
Series	Amp+?
IGBT Type	-
Configuration	Half Bridge
Voltage - Collector Emitter Breakdown (Max)	1200V
Current - Collector (Ic) (Max)	1130A
Power - Max	3060W
Vce(on) (Max) @ Vge, Ic	2.1V @ 15V, 600A
Current - Collector Cutoff (Max)	1mA
Input Capacitance (Cies) @ Vce	51nF @ 25V
Input	Standard
NTC Thermistor	Yes
Operating Temperature	-40°C ~ 150°C
Mounting Type	Chassis Mount
Package / Case	Module
Supplier Device Package	Module
	Report errors?

GSID600A120S4B1 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

GSID600A120S4B1 Payment Methods



















GSID600A120S4B1 Shipping Methods













If you have any question about GSID600A120S4B1, please do not hesitate to contact us!

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